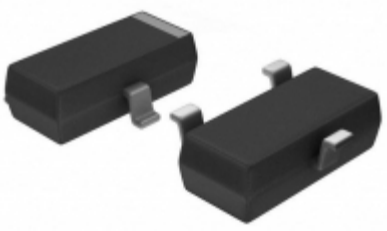
	<p>Hersteller-Teilenummer: SI2392ADS-T1-GE3</p>
	<p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p>
	<p>Teil der Beschreibung: MOSFET N-CH 100V 3.1A SOT-23</p>
	<p>Datenblätter:  SI2392ADS-T1-GE3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 77423 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	SI2392ADS-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 100V 3.1A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	77423 pcs Stock
detaillierte Beschreibung	N-Channel 100V 3.1A (Tc) 1.25W (Ta), 2.5W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.25W (Ta), 2.5W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.1A (Tc)
Rds On (Max) @ Id, Vgs	126 mOhm @ 2A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	10.4nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	196pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2392ADS-T1-GE3TR


















































SI2392ADS-T1-GE3 ist neu im Original, Suche SI2392ADS-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2392ADS-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2392ADS-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2377EDS-T1-GE3 Vishay / Siliconix MOSFET P-CH 20V 4.4A SOT-23</p>	 <p>SI2399 SIPU SI2399 SIPU</p>	 <p>SI2399CDS-T1-GE3 V SI2399CDS-T1-GE3 V</p>	 <p>SI2392DS-T1-E3 AOS SI2392DS-T1-E3 AOS</p>
 <p>SI2377EDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 4.4A SOT-23</p>	 <p>SI2392ADS-T1-E3 VISHAY SI2392ADS-T1-E3 VISHAY</p>	 <p>SI2377EDS-T1-E3 VISHAY SI2377EDS-T1-E3 VISHAY</p>	 <p>SI2392ADS-T1-GE3 Vishay / Siliconix MOSFET N-CH 100V 3.1A SOT-23</p>

heiße Teile

Mehr

 SI2365EDS-T1-GE3	 SI2365EDS-T1-GE3	 SI2366DS-T1-E3	 SI2366DS-T1-GE	 SI2366DS-T1-GE3
 SI2366DS-T1-GE3	 SI2367DS-T1-E3	 SI2367DS-T1-GE3	 SI2367DS-T1-GE3	 SI2369DS-T1-GE3
 SI2369DS-T1-GE3	 SI2371EDS-T1-GE3	 SI2371EDS-T1-GE3	 SI2372DS-T1-E3	 SI2372DS-T1-GE3
 SI2372DS-T1-GE3	 SI2374DS-T1-GE3	 SI2374DS-T1-GE3	 SI2377DS-T1-GE3	 SI2377EDS
 SI2377EDS-T1-E3	 SI2377EDS-T1-GE3	 SI2377EDS-T1-GE3	 SI2392ADS-T1-E3	 SI2392ADS-T1-GE3
 SI2392DS-T1-GE3	 SI2392DS-T1-GE3	 SI2399CDS-T1-GE3	 SI2399DS-T1-GE3	 SI2399DS-T1-GE3
 SI2400-BS	 SI2400-FS	 SI2400-FSR	 SI2400-KS	 SI2400-KSR
 SI2401-FS	 SI2401-FSR	 SI2401-FSR.	 SI2401-KS	 SI2403-FTR
 SI2404-C-FSR	 SI2404-C-FTR	 SI2404-C-ZSR	 SI2404-CFTRP	 SI2404-FS
 SI2404-FT	 SI2413AP	 SI2414-F-FTR	 SI2414-FT	 SI2414-FTR

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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